

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - 20 to 100 Volts
FORWARD CURRENT - 1.0 Ampere

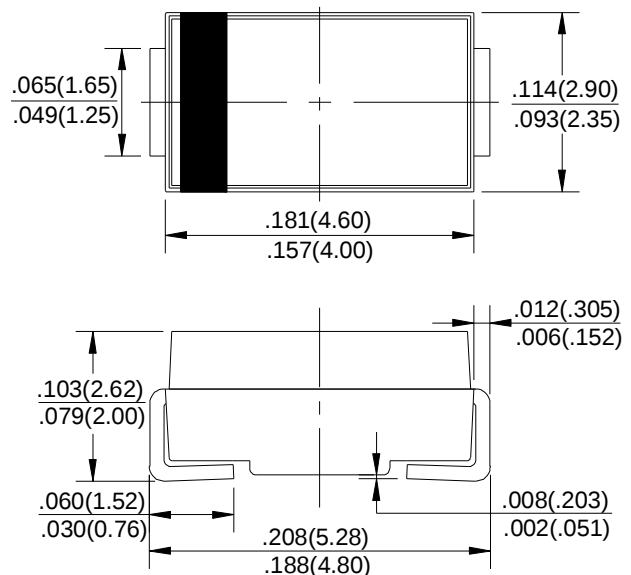
FEATURES

- For surface mounted applications
- Metal-Semiconductor junction with guarding
- Epitaxial construction
- Very low forward voltage drop
- High current capability
- Plastic material has UL flammability classification 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.

MECHANICAL DATA

- Case: Molded Plastic
- Polarity: Indicated by cathode band
- Weight: 0.002 ounces, 0.053 grams

SMA



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	SS12	SS13	SS14	SS15	SS16	SS18	SS110	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	20	30	40	50	60	80	100	V
Maximum RMS Voltage	VRMS	14	21	28	35	42	56	70	V
Maximum DC Blocking Voltage	VDC	20	30	40	50	60	80	100	V
Maximum Average Forward Rectified Current @TL=100 °C	I(AV)	1.0							A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed On Rated Load (JEDEC Method)	IFSM	30							A
Maximum Forward Voltage at 1.0A DC	VF	0.55			0.70		0.85		V
Maximum DC Reverse Current @Tj=25°C	IR	1.0							mA
at Rated DC Blocking Voltage @Tj=100°C		10							
Typical Junction Capacitance (Note1)	CJ	110							pF
Typical Thermal Resistance (Note2)	RθJL	20							°C/W
Operating Temperature Range	TJ	-55 to + 150							°C
Storage Temperature Range	TSTG	-55 to + 150							°C

NOTES:1.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

2.Thermal resistance junction to lead.

FIG. 1 - FORWARD CURRENT DERATING CURVE

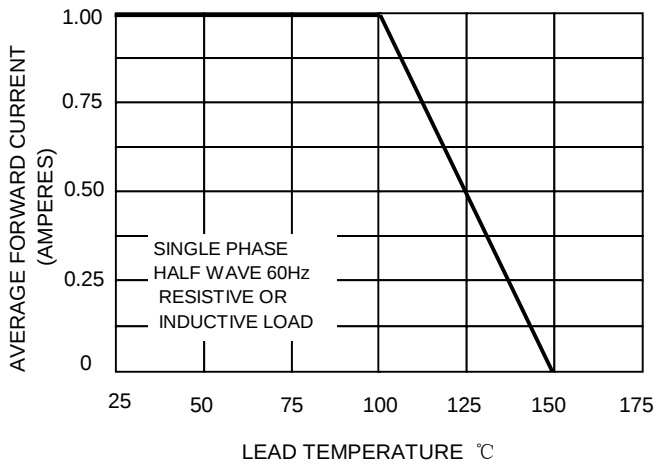


FIG. 2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

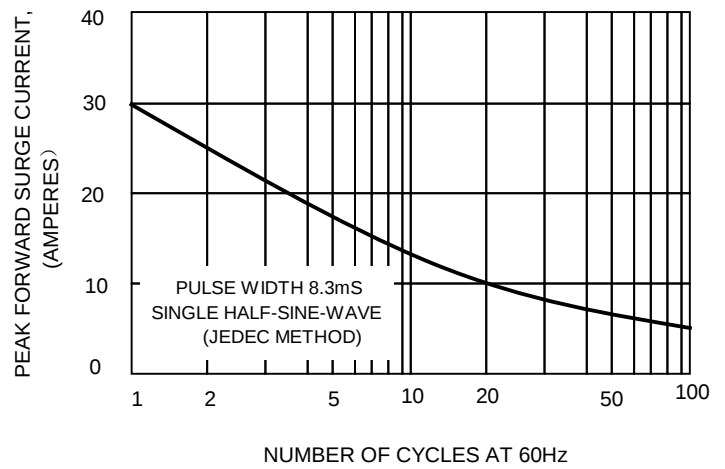


FIG.3-TYPICAL FORWARD CHARACTERISTICS

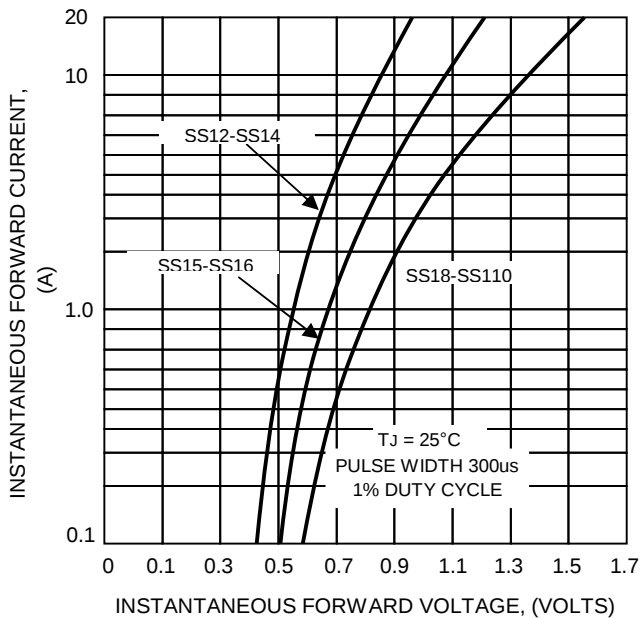


FIG.4-TYPICAL JUNCTION CAPACITANCE

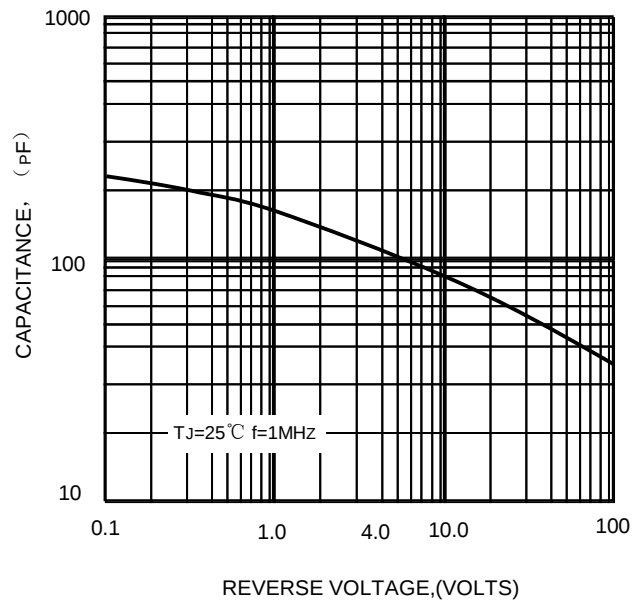


FIG.5-TYPICAL REVERSE CHARACTERISTICS

